NSN 5961-01-420-7747

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Thyristor Semiconductor Device - Page 1 of 1



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View Online at https://aerobasegroup.com/nsn/5961-01-420-7747	
Inclosure Material:	
Metal	
Overall Length:	
Between 0.240 inches and 0.260 inches	
Terminal Length:	
1.500 inches	
Overall Diameter:	
Between 0.335 inches and 0.370 inches	
Mounting Method:	
Terminal	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
600.0 repetitive peak reverse voltage and 600.0 repetitive peak off-state voltage and 600.0 nonrepetitive peak reverse voltage and 6.	0
peak gate voltage	
Current Rating Per Characteristic:	
1.60 amperes forward current, total rms horsepower metric and 1.00 amperes forward current, total rms universal and 120.00 ampere	s
peak forward surge current nanoamperes	
Power Rating Per Characteristic:	
0.1 watts small-signal input power, common-collector blank and 0.01 watts small-signal input power, common-collector universal	
Maximum Operating Tempurature Per Measurement Point:	
125.0 degrees celsius ambient air	
Test Data Document:	
96214-2693140 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,	etc
excludes any specification, standard or other document that may be referenced in a basic governing drawing)	
Terminal Type And Quantity:	
3 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Fiia:	